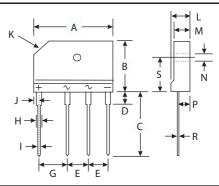


## KBJ10A THRU KBJ10M

CURRENT 10.0 Amperes VOLTAGE 50 to 1000 Volts

#### **Features**

- · Glass Passivated Die Construction
- · High Case Dielectric Strength of 1500VRMS
- · Low Reverse Leakage Current
- · Surge Overload Rating to 170A Peak
- · Ideal for Printed Circuit Board Applications
- · Plastic Material UL Flammability Classification 94V-0



### Mechanical Data

· Case: Molded Plastic

· Terminals : Plated Leads, Solderable per MIL-STD-202, Method 208

· Polarity: Molded on Body

· Mounting : Through Hole for #6 Screw · Mounting Torque : 5.0 in-lbs Maximum

Weight: 6.6 grams (approx.)Marking: Type Number

КВЈ										
Dim	Min	Max	Dim	Min	Max					
Α	29.70	30.30	J	2.30	2.70					
В	19.70	20.30	К	3.0 X 45°						
C	17.00	18.00	L	4.40	4.80					
D	3.80	4.20	М	3.40	3.80					
E	7.30	7.70	N	3.10	3.40					
G	9.80	10.20	Р	2.50	2.90					
Н	2.00	2.40	R	0.60	0.80					
I	0.90	1.10	S	10.80	11.20					
All Dimensions in mm										

## Maximum Ratings And Electrical Characteristics

(Ratings at 25  $^{\circ}$ C ambient temperature unless otherwise specified, Single phase, half wave 60Hz, resistive or inductive load. For capacitive load, derate by 20%)

		Symbols	KBJ 10A	KBJ 10B	KBJ 10D	KBJ 10G	KBJ 10J	KBJ 10K	KBJ 10M	Units
Peak Repetitive Reverse voltage Working Peak Reverse voltage DC Blocking voltage		Vrmm Vrwm Vr	50	100	200	400	600	800	1000	Volts
RMS Reverse voltage	VR(RMS)	35	70	140	280	420	560	700	Volts	
Average Rectified Output Current	lo	10						Amps		
Non-Repetitive Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)		lfsm	170						Amps	
Forward Voltage per element	@ IF=5.0 A	VFM	1.05						Volts	
Peak Reverse Current at Rated	@ Tc=25 ℃	l <sub>R</sub>	10 500							μA
DC Blocking voltage	@ Tc=125 ℃	IK								
I <sup>2</sup> t Rating for Fusing (t<8.3ms) (Note 1)		l <sup>2</sup> t	120						A <sup>2</sup> s	
Typical Junction Capacitance per element (Note 2)		Cj	55						pF	
Typical Thermal Resistance, Junction to Case (Note 3)		R⊖JA	4.0						°C/W	
Operating and Storage Temperature Range		Tj Tstg	-65 to +150						°C	

#### Notes

- (1) Non-repetitive, for t > 1.0ms and < 8.3ms.
- (2) Measured at 1.0MHz and Applied Reverse Voltage of 4.0V DC.
- (3) Thermal Resistance from junction to case per element. Unit mounted on 150 x 150 x 1.6mm copper plate heat sink.



# RATINGS AND CHARACTERISTIC CURVES KBJ10A THRU KBJ10M

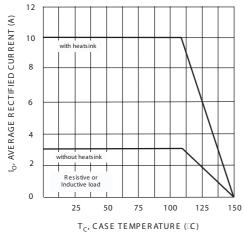


Fig. 1 Forward Current Derating Curve

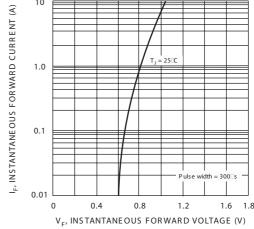
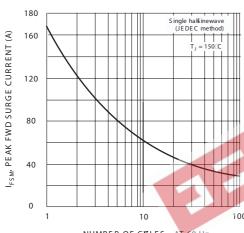
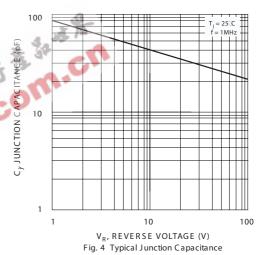


Fig. 2 Typical Forward Characteristics (per element)



NUMBER OF CCLES AT 60 Hz Fig. 3 Maimum NonRepetitive Surge Current



1000 IR, INSTANTANEOUS REVERSE CURRENπ(Δ) 100 10 1.0 = 25 0 0.1 20

PERCENT OF RATED PEAK REVERSE VOLTAGE (% Fig. 5 Typical Reverse Characteristics